

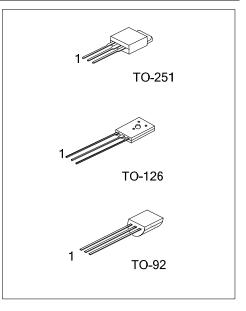
UT2274

NPN SILICON TRANSISTOR

SWITCHING REGULATOR APPLICATIONS

FEATURES

- * High breakdown voltage ($V_{CBO} \ge 1400V$).
- * Ultra high-speed switching.
- * Wide SOA.



ORDERING INFORMATION

Ordering Number		Deekere	Pin Assignment			Decking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UT2274L-T92-B	UT2274G-T92-B	TO-92	В	С	Е	Tape Box	
UT2274L-T92-K	UT2274G-T92-K	TO-92	В	С	Е	Bulk	
UT2274L-TM3-T	UT2274G-TM3-T	TO-251	В	С	Е	Tube	
UT2274L-T60-K	UT2274G-T60-K	TO-126	В	С	Е	Bulk	

Note: Pin assignment: E: Emitter B: Base C: Collector

UT2274 <u>Ģ-Т92</u> - <u></u>		
	(1)Packing Type	(1) B: Tape Box, K: Bulk, T: Tube
	(2)Package Type	(2) T92: TO-92, TM3: TO-251, T60: TO-126
	(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING

PACKAGE	MARKING				
TO-251	Lot Code \leftarrow UTC UT2274 \Box L: Lead Free G: Halogen Free D Data Code 1				
TO-126	UTC DDD Data Code UT2274 D L: Lead Free G: Halogen Free				
TO-92	UTC UT2274 G: Halogen Free Data Code				



■ **ABSOLUTE MAXIMUM RATINGS** (T_A= 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V _{CBO}	1400	V
Collector-Emitter Voltage		V _{CEO}	720	V
Emitter-Base Voltage		V _{EBO}	5	V
Collector Current	DC	Ιc	1	Α
	Pulse (Note 2)	I _{CP} 2		Α
Collector Dissipation	TO-251		1	W
	TO-92	Pc	625	
	TO-126		875	mW
Junction Temperature	Temperature T _J		150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

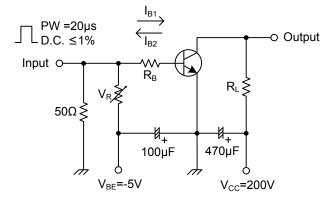
2. $P_W \leq 300 \mu s$, duty cycle $\leq 10\%$

■ ELECTRICAL CHARACTERISTICS (T_A= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =1 mA, I _E =0A	1400			V
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =5 mA, R _{BE} =∞	720			V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E =1 mA, I _C =0A	5			V
Collector Cut-off Current	I _{CBO}	V _{CB} =800 V, I _E =0A			10	μA
Collector Cut-off Current	I _{CES}	V _{CE} =1400 V, R _{BE} =0Ω			1	mA
Emitter Cut-off Current	I _{EBO}	V _{EB} =4V, I _C =0A			1	mA
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =0.25 A, I _B =0.05 A			1.5	V
Base-Emitter Saturation Voltage	V _{BE(SAT)}	I _C =0.5 A, I _B =0.1 A			1.5	V
DC Current Gain	h _{FE1}	V _{CE} =5V, I _C =0.1 A	15		35	
	h _{FE2}	V _{CE} =5V, I _C =0.5 A	4			
Storage Time	t _{stg}	V _{CC} =200V, R _L =400Ω		1.5	3.0	μs
Fall Time	t _F	I _C =0.5A,I _{B1} =0.1A,I _{B2} =-0.25A,		0.25	0.4	μs



SWITCHING TIME TEST CIRCUIT



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